

Description

The FDS6670A uses advanced trench technology to provide excellent RDS(ON), low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a

Battery protection or in other Switching application.



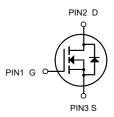
SOP-8

General Features

 $V_{DS} = 30V I_{D} = 18A$

 $R_{DS(ON)} < 6.5 \text{m}\Omega$ @ $V_{GS}=10V$

 $R_{DS(ON)} < 12m\Omega$ @ $V_{GS}=4.5V$



Application

Battery protection

Load switch

Uninterruptible power supply

N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
FDS6670A	SOP-8	HXY MOSFET	3000

Absolute Maximum Ratings (T_C=25 ℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
V _{DS}	Drain-Source Voltage	30	V
V _G s	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	18	А
I _D (70 °C)	Drain Current-Continuous(Tc=70℃)	8.2	А
Ідм	Pulsed Drain Current	42	Α
P _D	Maximum Power Dissipation	1.5	W
Т,,Тѕтс	Operating Junction and Storage Temperature Range	-55 To 150	$^{\circ}\!$
Rejc	Thermal Resistance,Junction-to-Case ^(Note 2)	36	°C/W



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	30			V	
$\triangle BV_{DSS}/\triangle T_{J}$	BVDSS Temperature Coefficient	Reference to 25°C , I _D =1mA		0.027		V/°C	
-	Static Drain-Source On-Resistance ²	V _{GS} =10V , I _D =10A	5.5 6.5		6.5	m0	
R _{DS(ON)}	Static Dialii-Source On-Resistance	V _{GS} =4.5V , I _D =8A		9	12	mΩ	
V _{GS(th)}	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =250uA	1.2	1.5	2.5	V	
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	VGS-VDS , ID -230UA		-5.8		mV/°C	
lana	Drain-Source Leakage Current	V _{DS} =24V , V _{GS} =0V , T _J =25°C			1		
I _{DSS}		V _{DS} =24V , V _{GS} =0V , T _J =55°C	['] / _{DS} =24V , V _{GS} =0V , T _J =55°C		5	- uA	
Igss	Gate-Source Leakage Current	$V_{GS}=\pm 20V$, $V_{DS}=0V$			±100	nA	
gfs	Forward Transconductance	V _{DS} =5V , I _D =10A		5.8		S	
Rg	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		2.2	3.8	Ω	
Qg	Total Gate Charge (4.5V)			12.6	17.6		
Qgs	Gate-Source Charge	V _{DS} =15V , V _{GS} =4.5V , I _D =10A		4.2	5.9	nC	
Q _{gd}	Gate-Drain Charge			5.1	7.1		
T _{d(on)}	Turn-On Delay Time			6.2	12.4		
Tr	Rise Time	V_{DD} =15V , V_{GS} =10V , R_{G} =3.3 Ω		59	106	ns	
T _{d(off)}	Turn-Off Delay Time	I _D =10A		27.6	55		
T _f	Fall Time			8.4	16.8		
Ciss	Input Capacitance			1317	1845		
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		163	228.2	pF	
Crss	Reverse Transfer Capacitance			131	183.4		
ls	Continuous Source Current ^{1,5}	\\ -\\ -0\\ Fama Comment		ļ	10.3	А	
I _{SM}	Pulsed Source Current ^{2,5}	──V _G =V _D =0V , Force Current			42	Α	
V _{SD}	Diode Forward Voltage ²	V _{GS} =0V , I _S =1A , T _J =25°C			1.2	V	
t _{rr}	Reverse Recovery Time			12.5		nS	
Q _{rr}	Reverse Recovery Charge	IF=10A , dl/dt=100A/μs , T _J =25°C		5		nC	

^{1.} The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.

^{2.}The data tested by pulsed , pulse width $\,\leq\,300\text{us}$, duty cycle $\,\leq\,2\%$

^{3.} The EAS data shows Max. rating . The test condition is V_{DD} =25V, V_{GS} =10V,L=0.1mH, I_{AS} =35A

^{4.}The power dissipation is limited by 150°C junction temperature

^{5.} The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.

Typical Characteristics

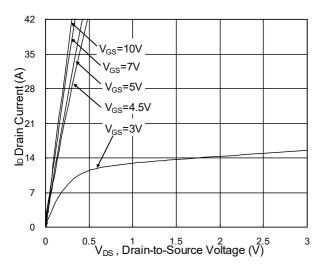


Fig.1 Typical Output Characteristics

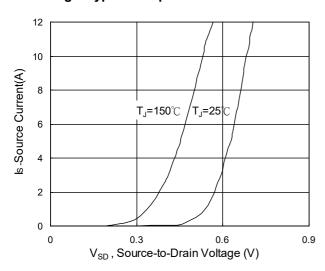


Fig.3 Forward Characteristics of reverse

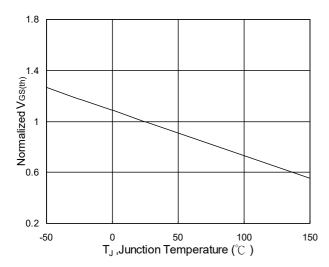


Fig.5 Normalized V_{GS(th)} vs. T_J

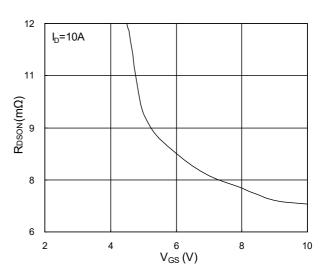


Fig.2 On-Resistance vs. Gate-Source

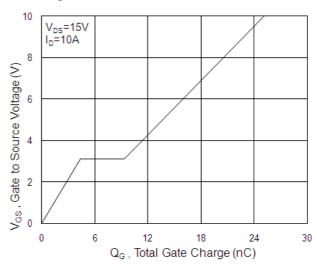


Fig.4 Gate-Charge Characteristics

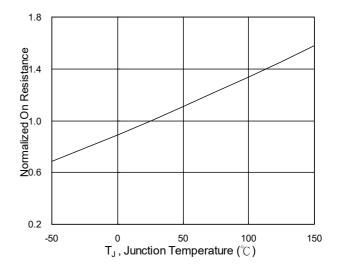
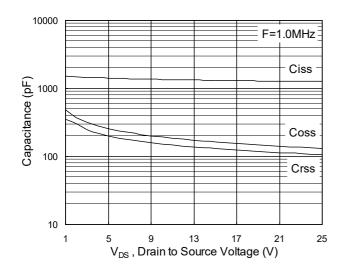


Fig.6 Normalized R_{DSON} vs. T_J



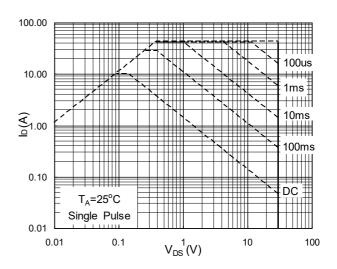


Fig.7 Capacitance

Fig.8 Safe Operating Area

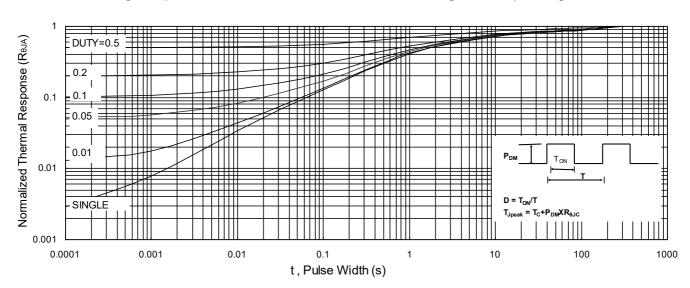


Fig.9 Normalized Maximum Transient Thermal Impedance

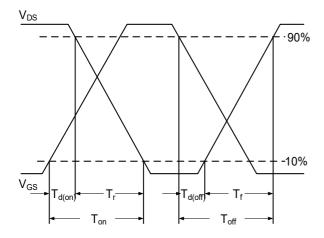


Fig.10 Switching Time Waveform

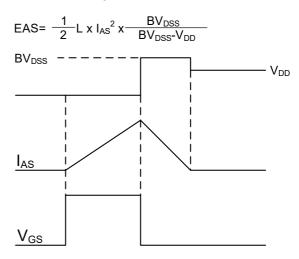
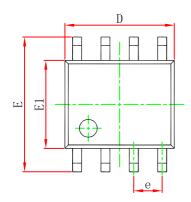
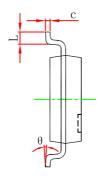
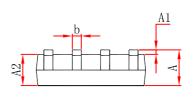


Fig.11 Unclamped Inductive Switching Waveform

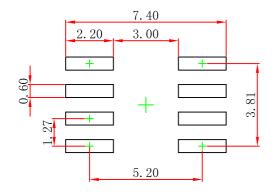
SOP-8 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1. 350	1.750	0.053	0.069	
A1	0.100	0. 250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
c	0.170	0.250	0.007	0.010	
D	4.800	5.000	0.189	0. 197	
e	1.270 (BSC)		0.050 (BSC)		
E	5.800	6. 200	0. 228	0. 244	
E1	3.800	4.000	0.150	0. 157	
L	0.400	1. 270	0.016	0.050	
θ	0°	8°	0°	8°	



- Note: 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.

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